# On the importance of atom probe tomography for the development of new nanoscale devices

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# Overview

- Fairly rare: 100 systems worldwide (reported in 2020 [1]).
- Unique. Provides spatial distribution of all elements with subnanometer resolution.
- Expensive. Requires complex sample preparation.
- Extremely useful for developing nanostructured devices.

[1] B. Gault, A. Chiaramonti, O. Cojocaru-Mirédin, et al., "Atom probe tomography", Nat. Rev. Methods Primers 1:51, pp. 1–30, 2021.

# Working principle

#### Field ion microscopy (FIM)

Time-of-flight secondary ion mass spectroscopy (ToF SIMS)



Shyam Katnagallu *et al* 2018 *J. Phys. D: Appl. Phys.* **51** 105601

Jan P. Hofmann et al, Phys. Chem. Chem. Phys., 2014,16, 5465-5474

# Working principle



- Sample is a truncated cone.
- Sample is evaporated by pulsed laser or voltage pulses.
- Evaporated particles are accelerated and detected by a 2D position-sensitive ToF mass spectometer.
- Raw data: ~10<sup>7</sup> particles identified by (x, y, t) and mass-to-charge ratio.
- Atom-by-atom reconstruction of sample. 4

#### Sample preparation – SEM/FIB





# Analysis: InAs/GaAs quantum dots







Stranski-krastanov quantum dots SKQDs



# Analysis: mass-to-charge ratio identification



#### Analysis: reconstructed image



#### 2D contour plot



#### Nearest neighbor analysis: Existence of clusters



#### Radial distribution analysis: Composition distribution



#### Correlation function: Degree of clusterization



#### Isosurface - SKQD

10%



17%



20%



#### Isosurface – c(4×4) SMLQD



15%

# **Cluster analysis**

Cluster parameters					
d-max (nm)	0.7				
Order (ions)	10				
N-min (ions)	200				
L (nm)	0.7				
d-erosion (nm)	0.4				

	In %	Extent x (nm)	Extent y (nm)	Extent z (nm)	Volume (nm <sup>3</sup> )
Matrix	7.5	-	-	-	-
Cluster 1	17.9	6.1	3.0	2.5	189
Cluster 2	18.7	9.4	6.5	2.2	551
Cluster 3	17.7	4.0	4.5	2.0	155
Cluster 4	18.1	2.9	5.1	2.4	150
Cluster 5	18.3	3.6	3.9	2.2	130
Cluster 6	18.9	4.4	2.4	2.5	113
Cluster 7	18.3	2.9	3.7	1.8	81
Cluster 8	16.6	5.3	3.5	1.8	139
Cluster 9	18.0	2.8	4.3	2.6	130
Cluster 10	19.0	4.7	4.9	2.4	232
Cluster 11	17.2	6.7	4.5	2.1	262

c(4×4) SMLQD

### Cluster analysis



Quantum well Thickness (nm)

# Final remarks

The only technique that provides 3D compositional information with nano or sub nanometer resolution.

 $\succ$  FIB/SEM to make a cone-shaped sample.

Sample is evaporated, collected, and reconstructed.

Analysis: stoichometry, cluster existence (nearest neighbor), concentration as a function of distance (radial distribution), degree of clusterization (correlation function), 3D shapes above a threshold concentraion (isosurface), cluster identification.

 $\blacktriangleright$  APT as simulation input.

Understanding nanostrucutres and nanodevices.